NSN 5961-01-279-8041

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-279-8041 **Inclosure Material:** Ceramic **Overall Length:** Between 0.595 inches and 0.620 inches **Overall Width:** Between 0.380 inches and 0.405 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ac **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 repetitive peak reverse voltage and 150.0 working peak reverse voltage **Current Rating Per Characteristic:** 15.00 amperes forward current, average and 30.00 amperes source cutoff current absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No